MCP6471

2 MHz, Low-Input Bias Current Op Amps

Features

- **Low Input Bias Current**
  - 150 pA (typical, T_A = +125°C)
- **Low Quiescent Current**
  - 100 µA/amplifier (typical)
- **Low Input Offset Voltage**
  - ±1.5 mV (maximum)
- Supply Voltage Range: 2.0V to 5.5V
- Rail-to-Rail Input/Output
- Gain Bandwidth Product: 2 MHz (typical)
- Slew Rate: 1.1 V/µs (typical)
- Unity Gain Stable
- No Phase Reversal
- Small Packages
  - Singles in SC70-5, SOT-23-5
- Extended Temperature Range
  - -40°C to +125°C

Applications

- Photodiode Amplifier
- pH Electrode Amplifier
- Low Leakage Amplifier
- Piezoelectric Transducer Amplifier
- Active Analog Filter
- Battery-Powered Signal Conditioning

Design Aids

- SPICE Macro Models
- FilterLab® Software
- MAPS (Microchip Advanced Part Selector)
- Analog Demonstration and Evaluation Boards
- Application Notes

Related Parts

- MCP6481: 4 MHz, Low Input Bias Current Op Amps
- MCP6491: 7.5 MHz, Low Input Bias Current Op Amps

Description

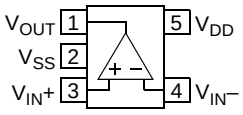
The Microchip's MCP6471 family of operational amplifiers (op amps) has low input bias current (150 pA, typical at 125°C) and rail-to-rail input and output operation. This family is unity gain stable and has a gain bandwidth product of 2 MHz (typical). These devices operate with a single-supply voltage as low as 2.0V, while only drawing 100 µA/amplifier (typical) of quiescent current. These features make the family of op amps well suited for photodiode amplifier, pH electrode amplifier, low leakage amplifier, and battery-powered signal conditioning applications, etc.

The MCP6471 family is offered in single (MCP6471) packages. All devices are designed using an advanced CMOS process and fully specified in extended temperature range from -40°C to +125°C.

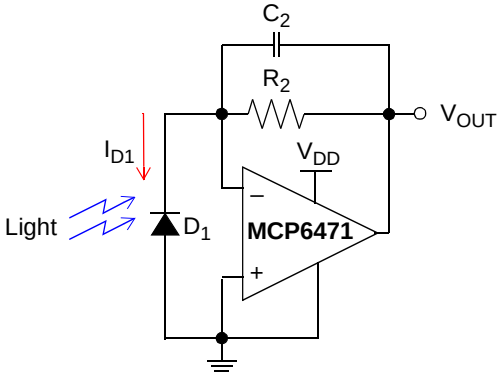
Package Types

MCP6471

SC70-5, SOT-23-5



Typical Application



Photodiode Amplifier

NOTES:

1.0 ELECTRICAL CHARACTERISTICS

1.1 Absolute Maximum Ratings †

$V_{DD} - V_{SS}$ 6.5V
Current at Input Pins .....±2 mA
Analog Inputs (V_{IN}+, V_{IN}-) (**Note 1**) .....V_{SS} – 1.0V to V_{DD} + 1.0V
All Other Inputs and Outputs .....V_{SS} – 0.3V to V_{DD} + 0.3V
Difference Input Voltage .....$V_{DD} - V_{SS}$
Output Short-Circuit Current .....continuous
Current at Output and Supply Pins .....±50 mA
Storage Temperature .....-65°C to +150°C
Maximum Junction Temperature (T_J) .....+150°C
ESD protection on all pins (HBM) .....≥ 4 kV

Note 1: See **Section 4.1.2, Input Voltage Limits.**

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

1.2 Specifications

TABLE 1-1: DC ELECTRICAL SPECIFICATIONS

Electrical Characteristics: Unless otherwise indicated, V_{DD} = +2.0V to +5.5V, V_{SS} = GND, T_A = +25°C, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $V_L = V_{DD}/2$ and R_L = 10 kΩ to V_L. (Refer to Figure 1-1).						
Parameters	**Sym.**	**Min.**	**Typ.**	**Max.**	**Units**	**Conditions**
Input Offset						
Input Offset Voltage	V_{OS}	-1.5	—	+1.5	mV	
Input Offset Drift with Temperature	$\Delta V_{OS}/\Delta T_A$	—	±2.5	—	µV/°C	T_A = -40°C to +125°C
Power Supply Rejection Ratio	PSRR	75	91	—	dB	$V_{CM} = V_{DD}/4$
Input Bias Current and Impedance						
Input Bias Current	I_B	—	±1	—	pA	
		—	8	—	pA	T_A = +85°C
		—	150	350	pA	T_A = +125°C
Input Offset Current	I_{OS}	—	±0.1	—	pA	
Common Mode Input Impedance	Z_{CM}	—	10^{13}||6	—	Ω||pF	
Differential Input Impedance	Z_{DIFF}	—	10^{13}||6	—	Ω||pF	
Common Mode						
Common Mode Input Voltage Range	V_{CMR}	V_{SS} - 0.3	—	V_{DD} + 0.3	V	
Common Mode Rejection Ratio	CMRR	65	83	—	dB	V_{CM} = -0.3V to 2.3V, V_{DD} = 2.0V
		70	88	—	dB	V_{CM} = -0.3V to 5.8V, V_{DD} = 5.5V
Open-Loop Gain						
DC Open-Loop Gain (Large Signal)	A_{OL}	95	115	—	dB	0.2V < V_{OUT} <(V_{DD} – 0.2V) V_{DD} = 5.5V, $V_{CM} = V_{SS}$

TABLE 1-1: DC ELECTRICAL SPECIFICATIONS (CONTINUED)

Electrical Characteristics: Unless otherwise indicated, V_{DD} = +2.0V to +5.5V, V_{SS} = GND, T_A = +25°C, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $V_L = V_{DD}/2$ and R_L = 10 kΩ to V_L. (Refer to Figure 1-1).						
Parameters	**Sym.**	**Min.**	**Typ.**	**Max.**	**Units**	**Conditions**
Output						
High-Level Output Voltage	V_{OH}	1.980	1.996	—	V	V_{DD} = 2.0V 0.5V input overdrive
		5.480	5.493	—	V	V_{DD} = 5.5V 0.5V input overdrive
Low-Level Output Voltage	V_{OL}	—	0.004	0.020	V	V_{DD} = 2.0V 0.5 V input overdrive
		—	0.007	0.020	V	V_{DD} = 5.5V 0.5 V input overdrive
Output Short-Circuit Current	I_{SC}	—	±10	—	mA	V_{DD} = 2.0V
		—	±32	—	mA	V_{DD} = 5.5V
Power Supply						
Supply Voltage	V_{DD}	2.0	—	5.5	V	
Quiescent Current per Amplifier	I_Q	50	100	200	µA	I_O = 0, $V_{CM} = V_{DD}/4$

TABLE 1-2: AC ELECTRICAL SPECIFICATIONS

Electrical Characteristics: Unless otherwise indicated, T_A = +25°C, V_{DD} = +2.0V to +5.5V, V_{SS} = GND, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $V_L = V_{DD}/2$, R_L = 10 kΩ to V_L and C_L = 20 pF. (Refer to Figure 1-1).						
Parameters	**Sym.**	**Min.**	**Typ.**	**Max.**	**Units**	**Conditions**
AC Response						
Gain Bandwidth Product	GBWP	—	2	—	MHz	
Phase Margin	PM	—	65	—	°	G = +1V/V
Slew Rate	SR	—	1.1	—	V/µs	
Noise						
Input Noise Voltage	E_{ni}	—	7	—	µVp-p	f = 0.1 Hz to 10 Hz
Input Noise Voltage Density	e_{ni}	—	27	—	nV/√Hz	f = 1 kHz
		—	23	—	nV/√Hz	f = 10 kHz
Input Noise Current Density	i_{ni}	—	0.6	—	fA/√Hz	f = 1 kHz

TABLE 1-3: TEMPERATURE SPECIFICATIONS

Electrical Characteristics: Unless otherwise indicated, V_{DD} = +2.0V to +5.5V and V_{SS} = GND.						
Parameters	**Sym.**	**Min.**	**Typ.**	**Max.**	**Units**	**Conditions**
Temperature Ranges						
Operating Temperature Range	T_A	-40	—	+125	°C	**Note 1**
Storage Temperature Range	T_A	-65	—	+150	°C	
Thermal Package Resistances						
Thermal Resistance, 5L-SC-70	θ_{JA}	—	331	—	°C/W	
Thermal Resistance, 5L-SOT-23	θ_{JA}	—	256	—	°C/W	

Note 1: The internal junction temperature (T_J) must not exceed the absolute maximum specification of +150°C.

1.3 Test Circuits

The circuit used for most DC and AC tests is shown in Figure 1-1. This circuit can independently set V_{CM} and V_{OUT} (refer to Equation 1-1). Note that V_{CM} is not the circuit's common mode voltage ($(V_P + V_M)/2$), and that V_{OST} includes V_{OS} plus the effects (on the input offset error, V_{OST}) of temperature, CMRR, PSRR and A_{OL}.

EQUATION 1-1:

$$G_{DM} = R_F / R_G$$
$$V_{CM} = (V_P + V_{DD}/2)/2$$
$$V_{OST} = V_{IN-} - V_{IN+}$$
$$V_{OUT} = (V_{DD}/2) + (V_P - V_M) + V_{OST} \cdot (1 + G_{DM})$$

Where:

G_{DM}	=	Differential Mode Gain	(V/V)
V_{CM}	=	Op Amp's Common Mode Input Voltage	(V)
V_{OST}	=	Op Amp's Total Input Offset Voltage	(mV)

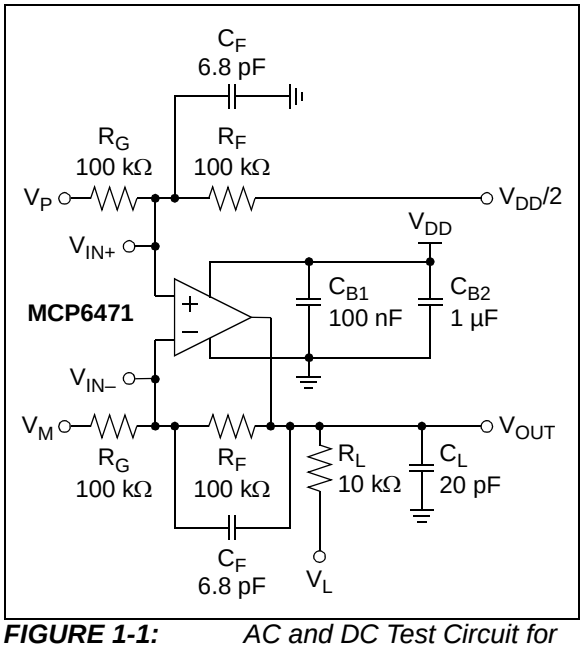


FIGURE 1-1: *AC and DC Test Circuit for Most Specifications.*

NOTES:

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

Note: Unless otherwise indicated, T_A = +25°C, V_{DD} = +2.0V to +5.5V, V_{SS} = GND, V_{CM} = V_{DD}/2, V_{OUT} ≈ V_{DD}/2, V_L = V_{DD}/2, R_L = 10 kΩ to V_L and C_L = 20 pF.

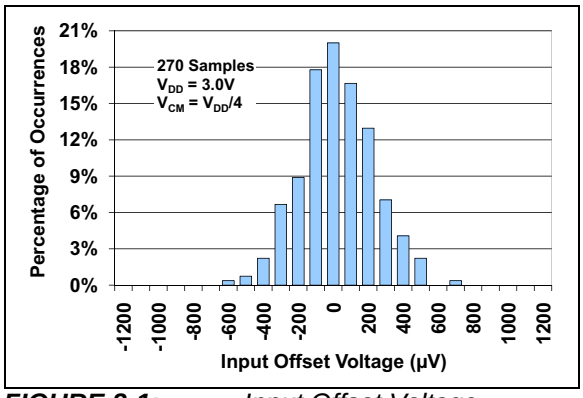


FIGURE 2-1: *Input Offset Voltage.*

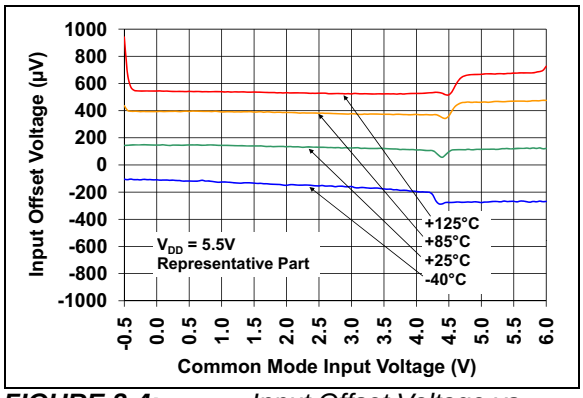


FIGURE 2-4: *Input Offset Voltage vs. Common Mode Input Voltage.*

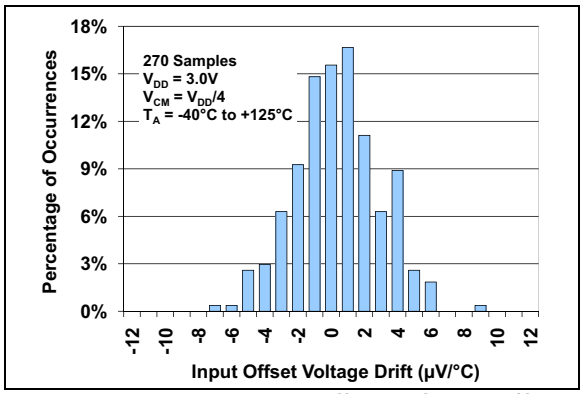


FIGURE 2-2: *Input Offset Voltage Drift.*

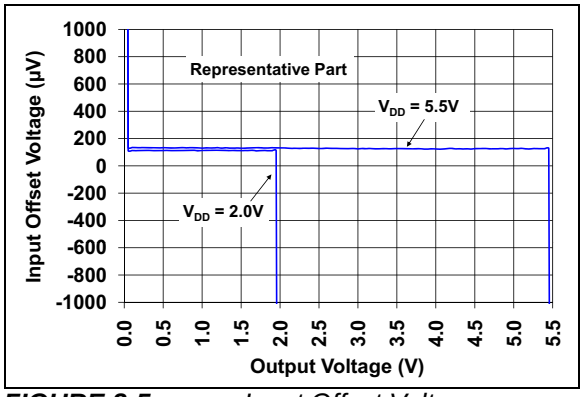


FIGURE 2-5: *Input Offset Voltage vs. Output Voltage.*

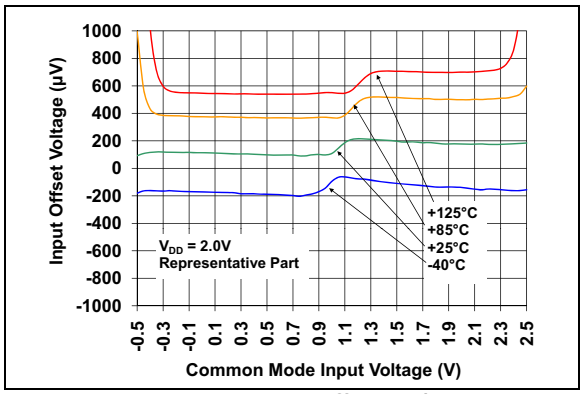


FIGURE 2-3: *Input Offset Voltage vs. Common Mode Input Voltage.*

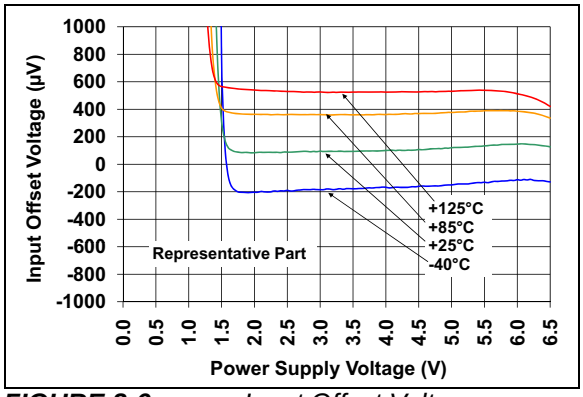


FIGURE 2-6: *Input Offset Voltage vs. Power Supply Voltage.*

Note: Unless otherwise indicated, T_A = +25°C, V_{DD} = +2.0V to +5.5V, V_{SS} = GND, V_{CM} = V_{DD}/2, V_{OUT} ≈ V_{DD}/2, V_L = V_{DD}/2, R_L = 10 kΩ to V_L and C_L = 20 pF.

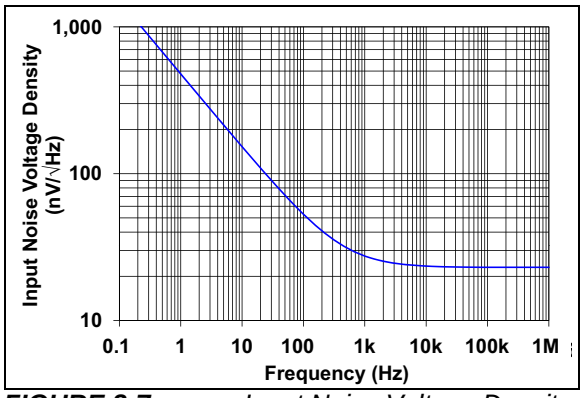


FIGURE 2-7: *Input Noise Voltage Density vs. Frequency.*

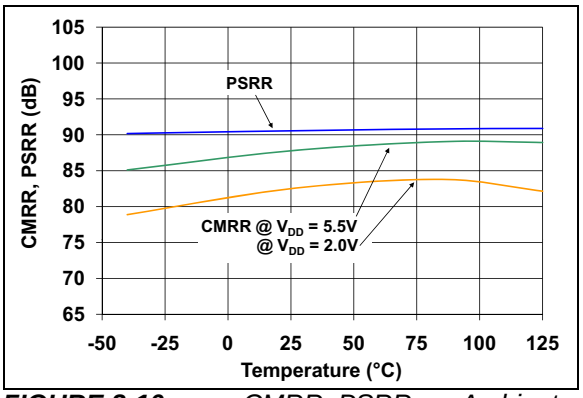


FIGURE 2-10: *CMRR, PSRR vs. Ambient Temperature.*

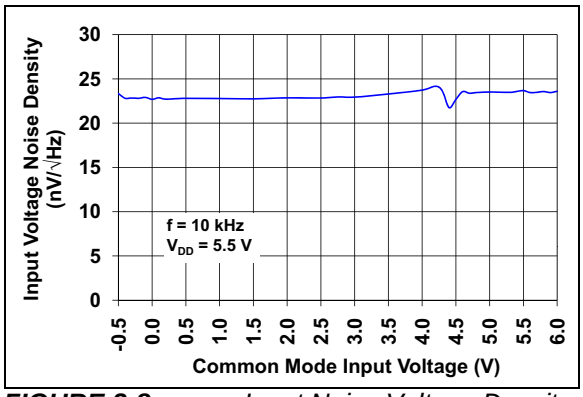


FIGURE 2-8: *Input Noise Voltage Density vs. Common Mode Input Voltage.*

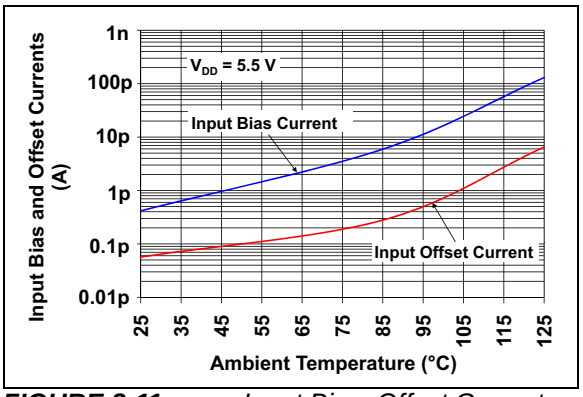


FIGURE 2-11: *Input Bias, Offset Currents vs. Ambient Temperature.*

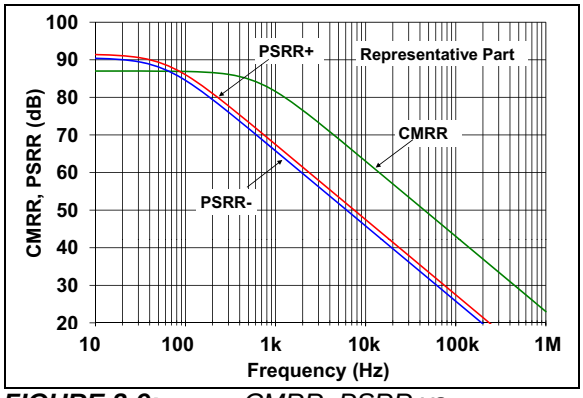


FIGURE 2-9: *CMRR, PSRR vs. Frequency.*

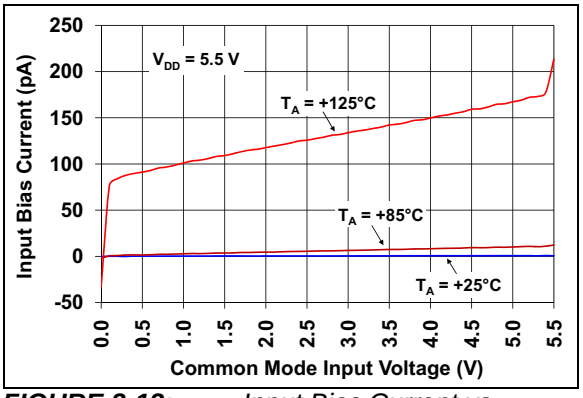


FIGURE 2-12: *Input Bias Current vs. Common Mode Input Voltage.*

Note: Unless otherwise indicated, T_A = +25°C, V_{DD} = +2.0V to +5.5V, V_{SS} = GND, V_{CM} = V_{DD}/2, V_{OUT} ≈ V_{DD}/2, V_L = V_{DD}/2, R_L = 10 kΩ to V_L and C_L = 20 pF.

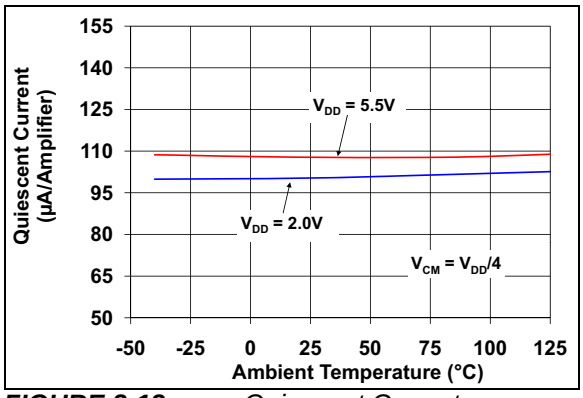


FIGURE 2-13: *Quiescent Current vs. Ambient Temperature.*

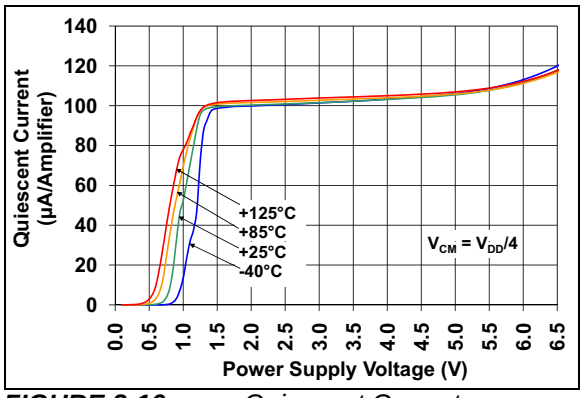


FIGURE 2-16: *Quiescent Current vs. Power Supply Voltage.*

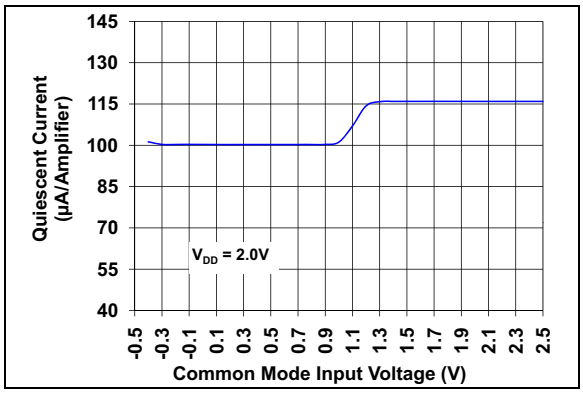


FIGURE 2-14: *Quiescent Current vs. Common Mode Input Voltage.*

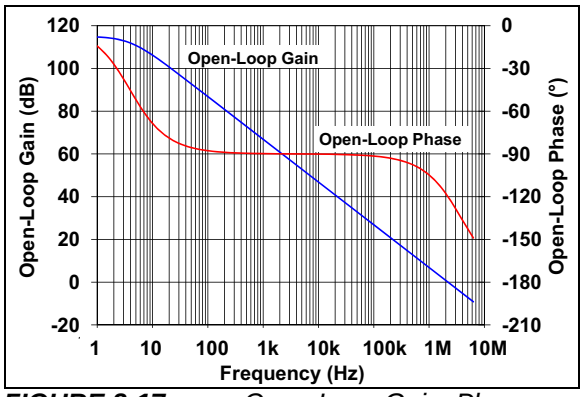


FIGURE 2-17: *Open-Loop Gain, Phase vs. Frequency.*

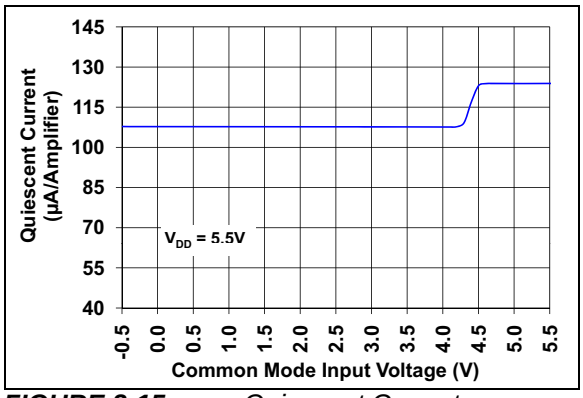


FIGURE 2-15: *Quiescent Current vs. Common Mode Input Voltage.*

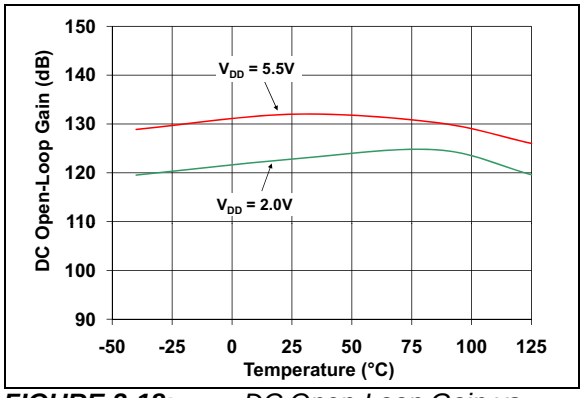


FIGURE 2-18: *DC Open-Loop Gain vs. Ambient Temperature.*

Note: Unless otherwise indicated, T_A = +25°C, V_{DD} = +2.0V to +5.5V, V_{SS} = GND, V_{CM} = V_{DD}/2, V_{OUT} ≈ V_{DD}/2, V_L = V_{DD}/2, R_L = 10 kΩ to V_L and C_L = 20 pF.

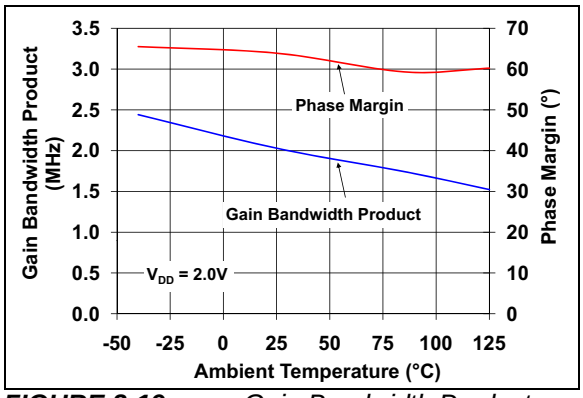


FIGURE 2-19: *Gain Bandwidth Product, Phase Margin vs. Ambient Temperature.*

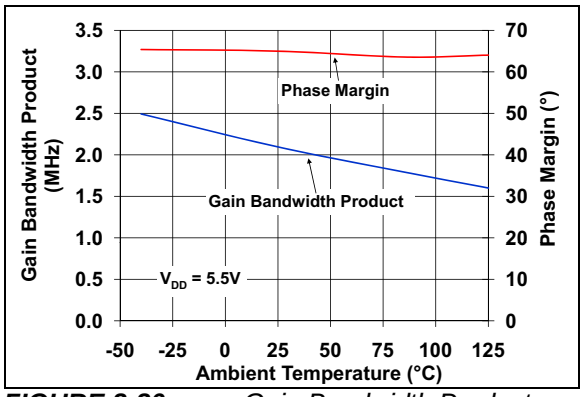


FIGURE 2-20: *Gain Bandwidth Product, Phase Margin vs. Ambient Temperature.*

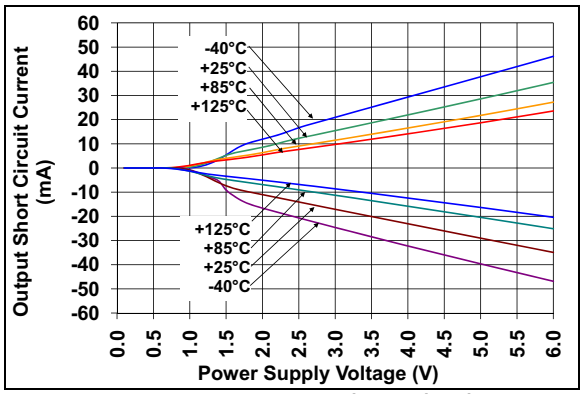


FIGURE 2-21: *Output Short Circuit Current vs. Power Supply Voltage.*

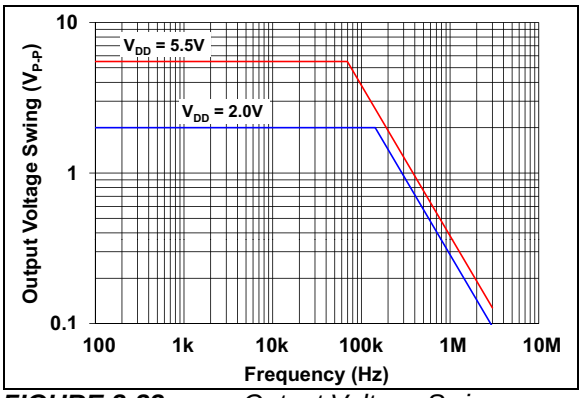


FIGURE 2-22: *Output Voltage Swing vs. Frequency.*

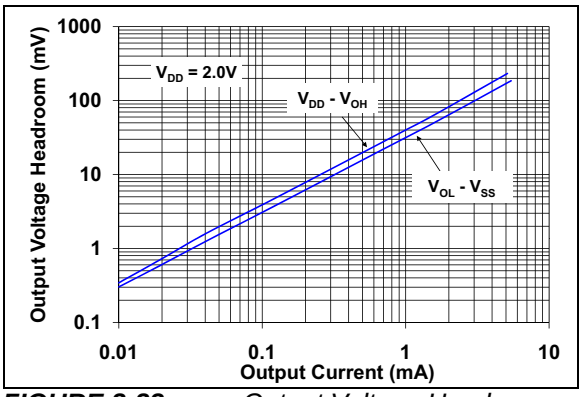


FIGURE 2-23: *Output Voltage Headroom vs. Output Current.*

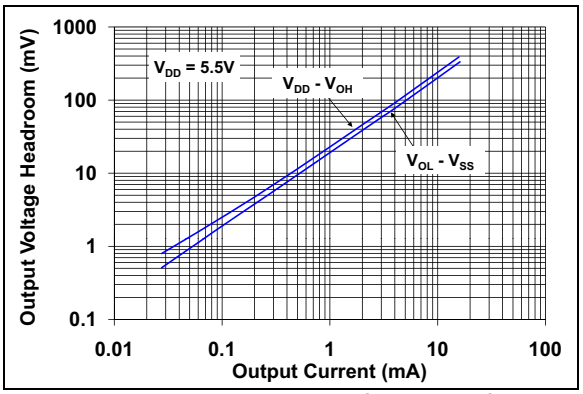


FIGURE 2-24: *Output Voltage Headroom vs. Output Current.*

Note: Unless otherwise indicated, T_A = +25°C, V_{DD} = +2.0V to +5.5V, V_{SS} = GND, V_{CM} = V_{DD}/2, V_{OUT} ≈ V_{DD}/2, V_L = V_{DD}/2, R_L = 10 kΩ to V_L and C_L = 20 pF.

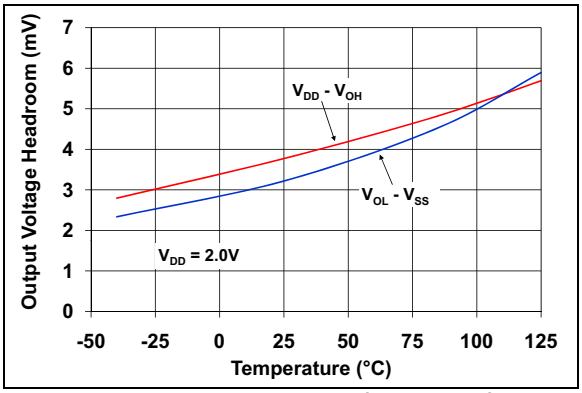


FIGURE 2-25: *Output Voltage Headroom vs. Ambient Temperature.*

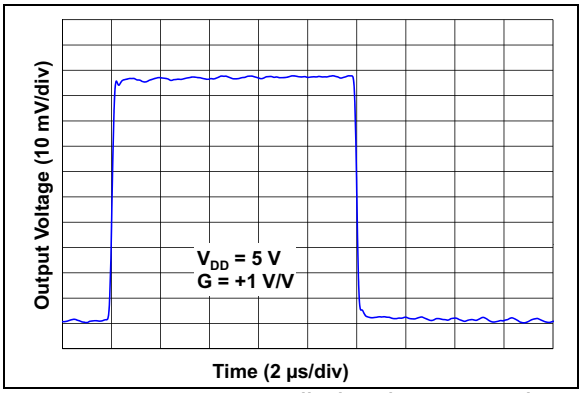


FIGURE 2-28: *Small Signal Non-Inverting Pulse Response.*

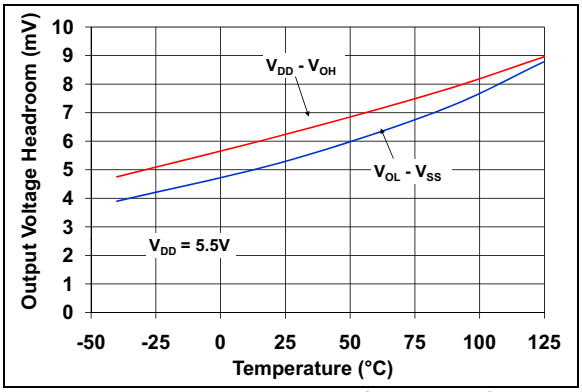


FIGURE 2-26: *Output Voltage Headroom vs. Ambient Temperature.*

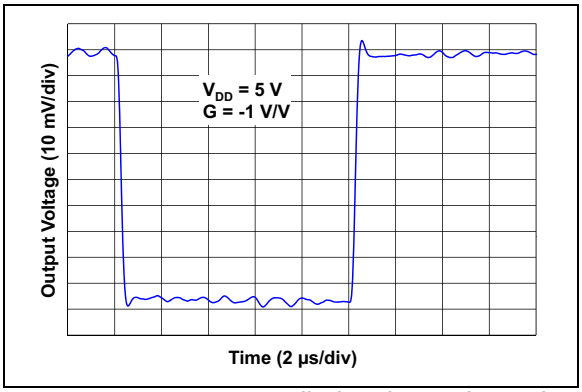


FIGURE 2-29: *Small Signal Inverting Pulse Response.*

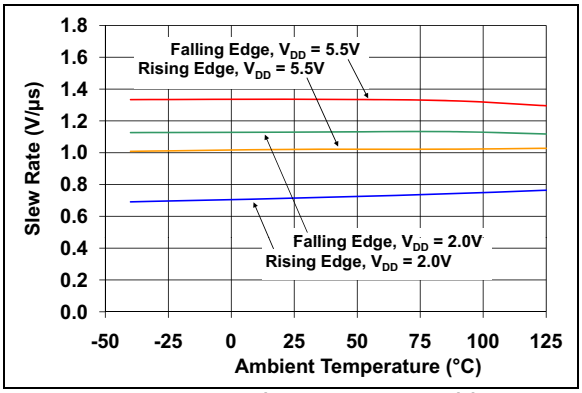


FIGURE 2-27: *Slew Rate vs. Ambient Temperature.*

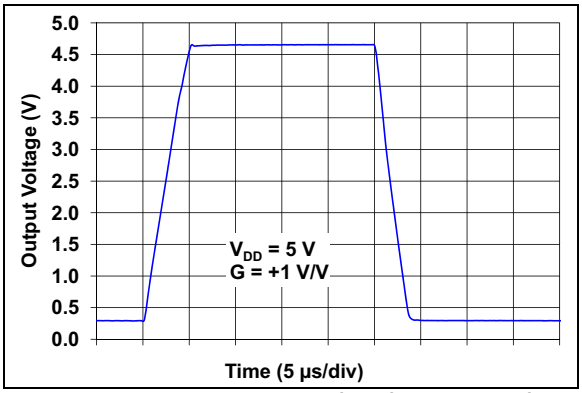


FIGURE 2-30: *Large Signal Non-Inverting Pulse Response.*

Note: Unless otherwise indicated, T_A = +25°C, V_{DD} = +2.0V to +5.5V, V_{SS} = GND, V_{CM} = V_{DD}/2, V_{OUT} ≈ V_{DD}/2, V_L = V_{DD}/2, R_L = 10 kΩ to V_L and C_L = 20 pF.

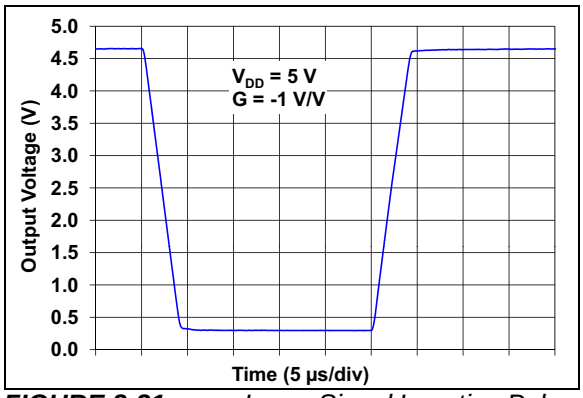


FIGURE 2-31: *Large Signal Inverting Pulse Response.*

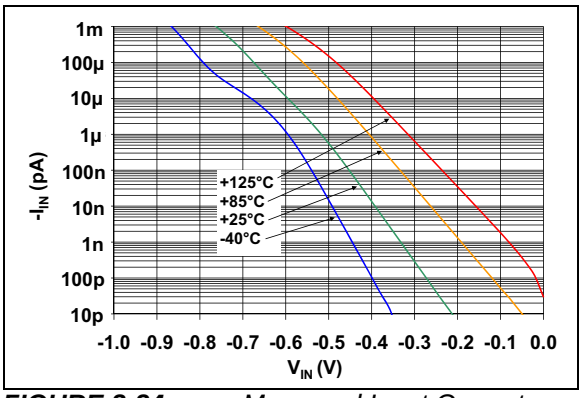


FIGURE 2-34: *Measured Input Current vs. Input Voltage (below V_{SS}).*

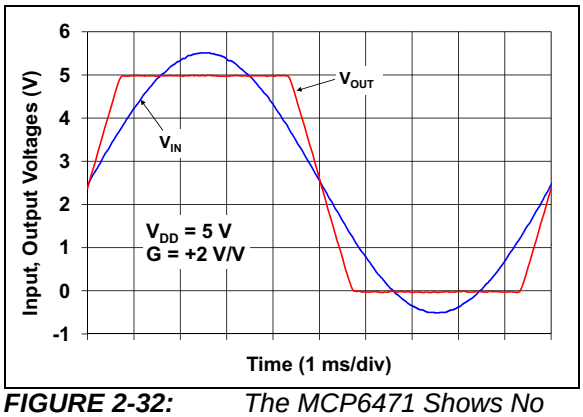


FIGURE 2-32: *The MCP6471 Shows No Phase Reversal.*

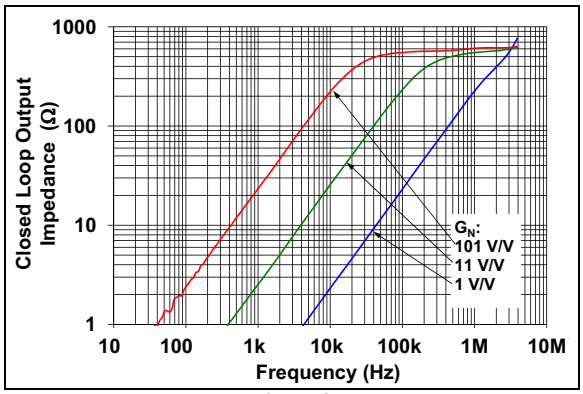


FIGURE 2-33: *Closed Loop Output Impedance vs. Frequency.*

3.0 PIN DESCRIPTIONS

Descriptions of the pins are listed in Table 3-1.

TABLE 3-1: PIN FUNCTION TABLE

MCP6471	Symbol	Description
SC70-5, SOT-23-5		
1	V_{OUT}	Output
2	V_{SS}	Negative Power Supply
3	$V_{IN}+$	Non-inverting Input
4	$V_{IN}–$	Inverting Input
5	V_{DD}	Positive Power Supply

3.1 Analog Outputs

The output pins are low-impedance voltage sources.

3.2 Analog Inputs

The non-inverting and inverting inputs are high-impedance CMOS inputs with low bias currents.

3.3 Power Supply Pins

The positive power supply (V_{DD}) is 2.0V to 5.5V higher than the negative power supply (V_{SS}). For normal operation, the other pins are at voltages between V_{SS} and V_{DD}.

Typically, these parts are used in single-supply operation. In this case, V_{SS} is connected to ground and V_{DD} is connected to the supply. V_{DD} will need bypass capacitors.

NOTES:

4.0 APPLICATION INFORMATION

The MCP6471 family of op amps is manufactured using Microchip's state-of-the-art CMOS process and is specifically designed for low-power, high-precision applications.

4.1 Inputs

4.1.1 PHASE REVERSAL

The MCP6471 op amps are designed to prevent phase reversal when the input pins exceed the supply voltages. Figure 2-32 shows the input voltage exceeding the supply voltage without any phase reversal.

4.1.2 INPUT VOLTAGE LIMITS

In order to prevent damage and/or improper operation of these amplifiers, the circuit must limit the voltages at the input pins (see **Section 1.1 "Absolute Maximum Ratings †"**).

The ESD protection on the inputs can be depicted as shown in Figure 4-1. This structure was chosen to protect the input transistors against many (but not all) overvoltage conditions, and to minimize the input bias current (I_B).

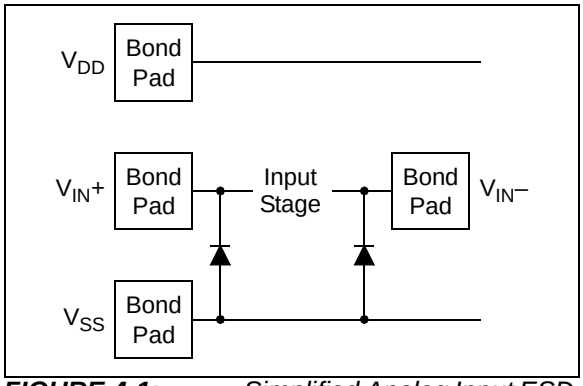


FIGURE 4-1: *Simplified Analog Input ESD Structures.*

The input ESD diodes clamp the inputs when they try to go more than one diode drop below V_{SS}. They also clamp any voltages that go well above V_{DD}. Their breakdown voltage is high enough to allow normal operation, but not low enough to protect against slow overvoltage (beyond V_{DD}) events. Very fast ESD events (that meet the specification) are limited so that damage does not occur.

In some applications, it may be necessary to prevent excessive voltages from reaching the op amp inputs; Figure 4-2 shows one approach to protecting these inputs.

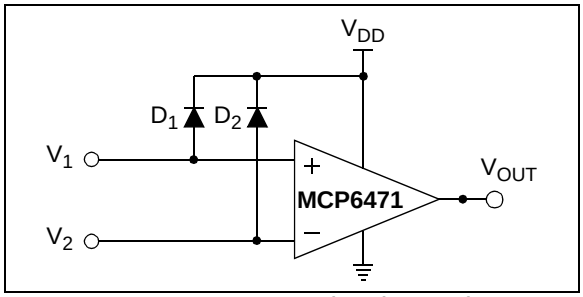


FIGURE 4-2: *Protecting the Analog Inputs.*

A significant amount of current can flow out of the inputs when the common mode voltage (V_{CM}) is below ground (V_{SS}), as shown in Figure 2-34.

4.1.3 INPUT CURRENT LIMITS

In order to prevent damage and/or improper operation of these amplifiers, the circuit must limit the currents into the input pins (see **Section 1.1 "Absolute Maximum Ratings †"**).

Figure 4-3 shows one approach to protecting these inputs. The resistors R_1 and R_2 limit the possible currents in or out of the input pins (and the ESD diodes, D_1 and D_2). The diode currents will go through either V_{DD} or V_{SS}.

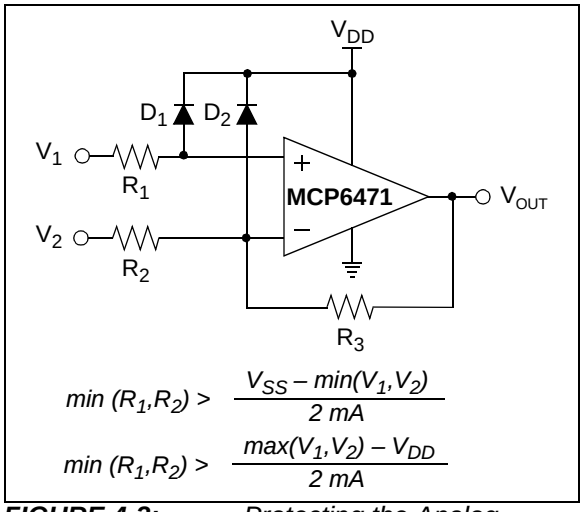


FIGURE 4-3: *Protecting the Analog Inputs.*

4.1.4 NORMAL OPERATION

The inputs of the MCP6471 op amps use two differential input stages in parallel. One operates at a low common mode input voltage (V_{CM}), while the other operates at a high V_{CM}. With this topology, the device operates with a V_{CM} up to 0.3V above V_{DD} and 0.3V below V_{SS} (refer to Figures 2-3 and 2-4). The input offset voltage is measured at $V_{CM} = V_{SS} - 0.3V$ and $V_{DD} + 0.3V$ to ensure proper operation.

The transition between the input stages occurs when V_{CM} is near $V_{DD} - 1.1V$ (refer to Figures 2-3 and 2-4). For the best distortion performance and gain linearity, with non-inverting gains, avoid this region of operation.

4.2 Rail-to-Rail Output

The output voltage range of the MCP6471 op amps is 0.007V (typical) and 5.493V (typical) when $R_L = 10\ k\Omega$ is connected to $V_{DD}/2$ and $V_{DD} = 5.5V$. Refer to Figures 2-23 and 2-24 for more information.

4.3 Capacitive Loads

Driving large capacitive loads can cause stability problems for voltage feedback op amps. As the load capacitance increases, the feedback loop's phase margin decreases and the closed-loop bandwidth is reduced. This produces gain peaking in the frequency response, with overshoot and ringing in the step response. While a unity-gain buffer (G = +1V/V) is the most sensitive to capacitive loads, all gains show the same general behavior.

When driving large capacitive loads with these op amps (e.g., > 100 pF when G = + 1V/V), a small series resistor at the output (R_{ISO} in Figure 4-4) improves the feedback loop's phase margin (stability) by making the output load resistive at higher frequencies. The bandwidth will generally be lower than the bandwidth with no capacitance load.

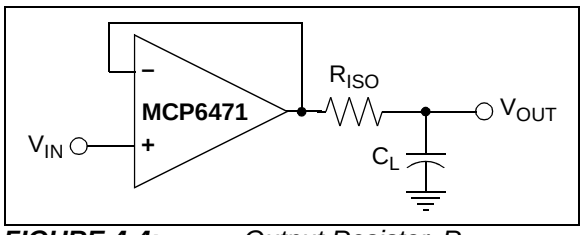


FIGURE 4-4: *Output Resistor, R_{ISO} Stabilizes Large Capacitive Loads.*

Figure 4-5 gives the recommended R_{ISO} values for different capacitive loads and gains. The x-axis is the normalized load capacitance (C_L/G_N), where G_N is the circuit's noise gain. For non-inverting gains, G_N and the Signal Gain are equal. For inverting gains, G_N is 1 + |Signal Gain| (e.g., -1V/V gives G_N = +2V/V).

After selecting R_{ISO} for your circuit, double check the resulting frequency response peaking and step response overshoot. Modify R_{ISO}'s value until the response is reasonable. Bench evaluation and simulations with the MCP6471 SPICE macro model are helpful.

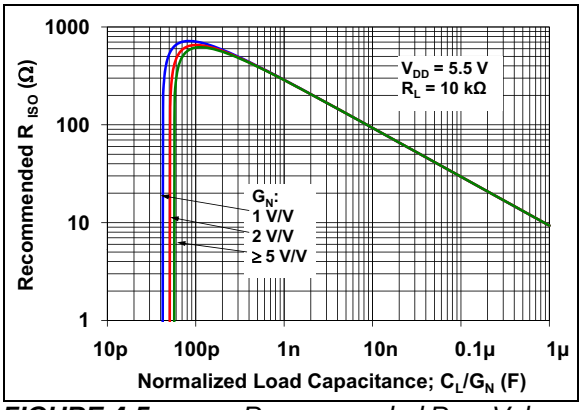


FIGURE 4-5: *Recommended R_{ISO} Values for Capacitive Loads.*

4.4 Supply Bypass

With this family of operational amplifiers, the power supply pin (V_{DD} for single supply) should have a local bypass capacitor (i.e., 0.01 µF to 0.1 µF) within 2 mm for good high-frequency performance. It can use a bulk capacitor (i.e., 1 µF or larger) within 100 mm to provide large, slow currents. This bulk capacitor can be shared with other analog parts.

4.5 PCB Surface Leakage

In applications where low input bias current is critical, PCB surface leakage effects need to be considered. Surface leakage is caused by humidity, dust or other contamination on the board. Under low-humidity conditions, a typical resistance between nearby traces is $10^{12}\Omega$. A 5V difference would cause 5 pA of current to flow; which is greater than the MCP6471 family's bias current at +25°C (1 pA, typical).

The easiest way to reduce surface leakage is to use a guard ring around sensitive pins (or traces). The guard ring is biased at the same voltage as the sensitive pin. An example of this type of layout is shown in Figure 4-6.

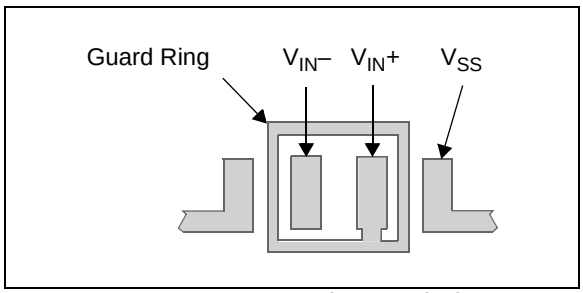


FIGURE 4-6: *Example Guard Ring Layout for Inverting Gain.*

1. Non-Inverting Gain and Unity-Gain Buffer:
   a. Connect the non-inverting pin (V_{IN}+) to the input with a wire that does not touch the PCB surface.
   b. Connect the guard ring to the inverting input pin (V_{IN}–). This biases the guard ring to the Common mode input voltage.
2. Inverting Gain and Transimpedance Gain Amplifiers (convert current to voltage, such as photo detectors):
   a. Connect the guard ring to the non-inverting input pin (V_{IN}+). This biases the guard ring to the same reference voltage as the op amp (e.g., V_{DD}/2 or ground).
   b. Connect the inverting pin (V_{IN}–) to the input with a wire that does not touch the PCB surface.

4.6 Application Circuits

4.6.1 PHOTO DETECTION

The MCP6471 op amps can be used to easily convert the signal from a sensor that produces an output current (such as a photo diode) into a voltage (a transimpedance amplifier). This is implemented with a single resistor (R_2) in the feedback loop of the amplifiers shown in Figure 4-7 and Figure 4-8. The optional capacitor (C_2) sometimes provides stability for these circuits.

A photodiode configured in the Photovoltaic mode has zero voltage potential placed across it (Figure 4-7). In this mode, the light sensitivity and linearity is maximized, making it best suited for precision applications. The key amplifier specifications for this application are: low input bias current, common mode input voltage range (including ground), and rail-to-rail output.

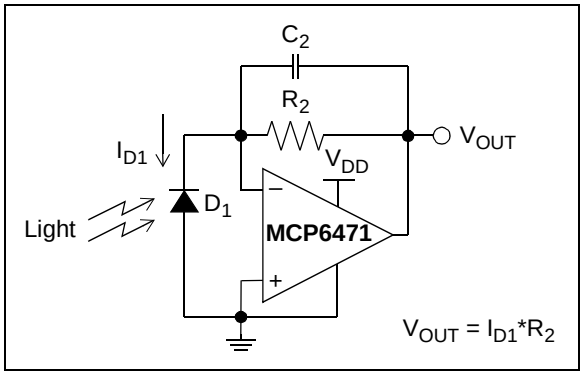


FIGURE 4-7: *Photovoltaic Mode Detector.*

In contrast, a photodiode that is configured in the Photoconductive mode has a reverse bias voltage across the photo-sensing element (Figure 4-8). This decreases the diode capacitance, which facilitates high-speed operation (e.g., high-speed digital communications). The design trade-off is increased diode leakage current and linearity errors. The op amp needs to have a wide Gain Bandwidth Product (GBWP).

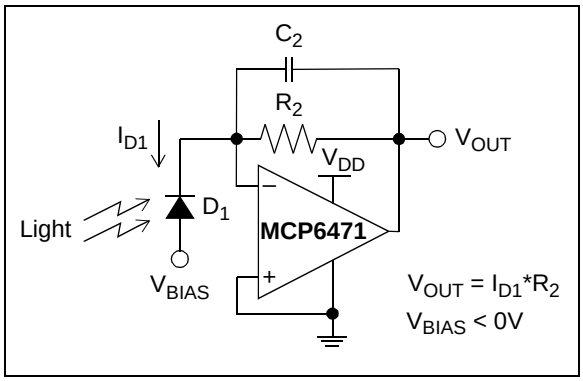


FIGURE 4-8: *Photoconductive Mode Detector.*

4.6.2 ACTIVE LOW PASS FILTER

The MCP6471 op amp's low input bias current makes it possible for the designer to use larger resistors and smaller capacitors for active low-pass filter applications. However, as the resistance increases, the noise generated also increases. Parasitic capacitances and the large value resistors could also modify the frequency response. These trade-offs need to be considered when selecting circuit elements.

Usually, the op amp bandwidth is 100x the filter cutoff frequency (or higher) for good performance. It is possible to have the op amp bandwidth 10x higher than the cutoff frequency, thus having a design that is more sensitive to component tolerances.

Figure 4-9 and Figure 4-10 show low-pass, second-order, Butterworth filters with a cutoff frequency of 10 Hz. The filter in Figure 4-9 has a non-inverting gain of +1 V/V, and the filter in Figure 4-10 has an inverting gain of -1 V/V.

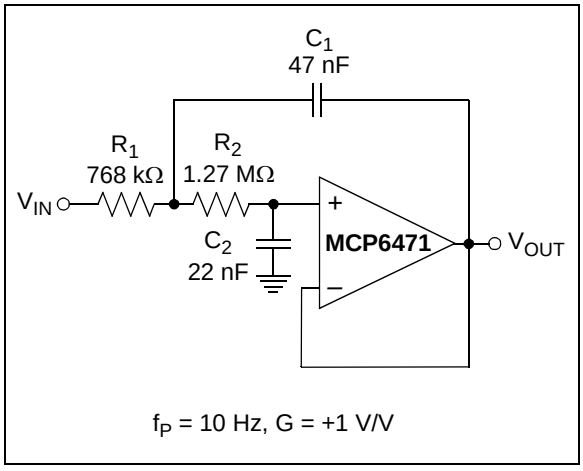


FIGURE 4-9: *Second-Order, Low-Pass Butterworth Filter with Sallen-Key Topology.*

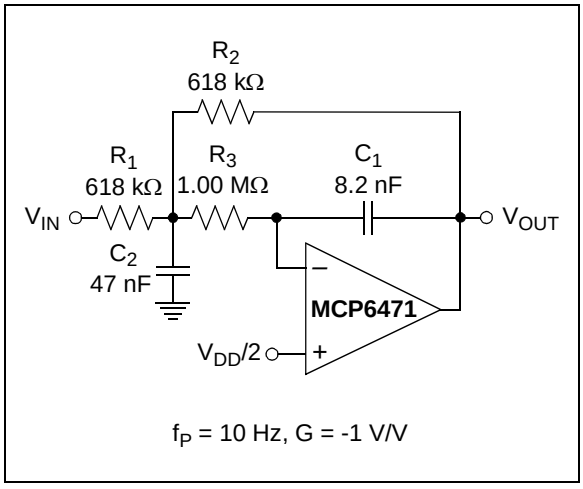


FIGURE 4-10: *Second-Order, Low-Pass Butterworth Filter with Multiple-Feedback Topology.*

4.6.3 PH ELECTRODE AMPLIFIER

The MCP6471 op amp can be used for sensing applications where sensor has high output impedance, such as pH electrode sensor, its output impedance is in the range of 1 MΩ to 1GΩ. The key op amp specifications for this kind of applications are low input bias current and high input impedance.

A typical sensing circuit is shown in Figure 4-11, it is implemented with a non-inverting amplifier which has a gain of $1+R_2/R_1$. The input voltage error due to input bias current is equal to I_B*R_{OUT}, which is amplified by $1+R_2/R_1$ at the output. As thus, to minimize the voltage error and get the V_{OUT} with better accuracy, the I_B must be small enough.

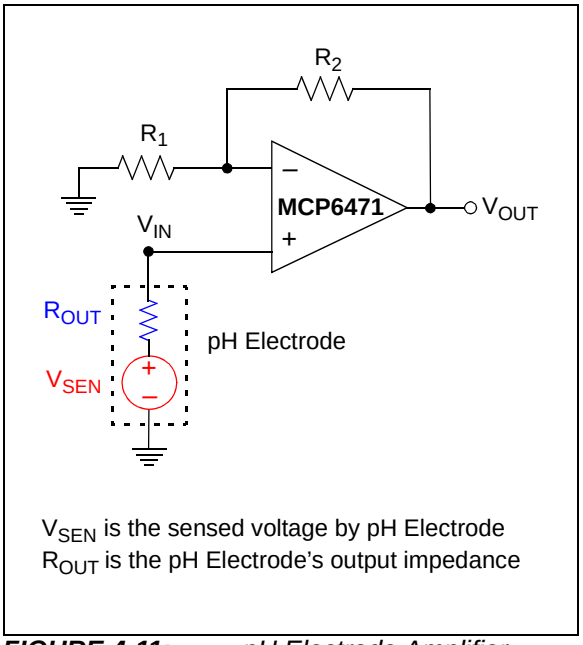


FIGURE 4-11: *pH Electrode Amplifier.*

5.0 DESIGN AIDS

Microchip Technology Inc. provides the basic design tools needed for the MCP6471 family of op amps.

5.1 SPICE Macro Model

The latest SPICE macro model for the MCP6471 op amp is available on the Microchip web site at www.microchip.com. The model was written and tested in PSpice, owned by Orcad (Cadence®). For other simulators, translation may be required.

The model covers a wide aspect of the op amp's electrical specifications. Not only does the model cover voltage, current and resistance of the op amp, but it also covers the temperature and noise effects on the behavior of the op amp. The model has not been verified outside the specification range listed in the op amp data sheet. The model behaviors under these conditions cannot be guaranteed to match the actual op amp performance.

Moreover, the model is intended to be an initial design tool. Bench testing is a very important part of any design and cannot be replaced with simulations. Also, simulation results using this macro model need to be validated by comparing them to the data sheet specifications and characteristic curves.

5.2 FilterLab Software

Microchip's FilterLab software is an innovative software tool that simplifies analog active filter (using op amps) design. Available at no cost from the Microchip web site at www.microchip.com/filterlab, the FilterLab design tool provides full schematic diagrams of the filter circuit with component values. It also outputs the filter circuit in SPICE format, which can be used with the macro model to simulate actual filter performance.

5.3 MAPS (Microchip Advanced Part Selector)

MAPS is a software tool that helps semiconductor professionals efficiently identify Microchip devices that fit a particular design requirement. Available at no cost, MAPS is an overall selection tool for Microchip's product portfolio that includes analog, memory, MCUs and DSCs. Using this tool, you can define a filter to sort features for a parametric search of devices and export side-by-side technical comparison reports. Helpful links are also provided for data sheets, purchases and sampling of Microchip parts. The web site is available at www.microchip.com/maps.

5.4 Analog Demonstration and Evaluation Boards

Microchip offers a broad spectrum of Analog Demonstration and Evaluation Boards that are designed to help you achieve faster time to market. For a complete listing of these boards and their corresponding user's guides and technical information, visit the Microchip web site: www.microchip.com/analogtools.

Some boards that are especially useful include:

- MCP6XXX Amplifier Evaluation Board 1
- MCP6XXX Amplifier Evaluation Board 2
- MCP6XXX Amplifier Evaluation Board 3
- MCP6XXX Amplifier Evaluation Board 4
- Active Filter Demo Board Kit
- 5/6-Pin SOT-23 Evaluation Board, part number VSUPEV2
- 8-Pin SOIC/MSOP/TSSOP/DIP Evaluation Board, part number SOIC8EV

5.5 Application Notes

The following Microchip analog design note and application notes are available on the Microchip web site at www.microchip.com/appnotes, and are recommended as supplemental reference resources.

- **ADN003:** *"Select the Right Operational Amplifier for your Filtering Circuits",* DS21821
- **AN722:** *"Operational Amplifier Topologies and DC Specifications",* DS00722
- **AN723:** *"Operational Amplifier AC Specifications and Applications",* DS00723
- **AN884:** *"Driving Capacitive Loads With Op Amps",* DS00884
- **AN990:** *"Analog Sensor Conditioning Circuits – An Overview",* DS00990
- **AN1177:** *"Op Amp Precision Design: DC Errors",* DS01177
- **AN1228:** *"Op Amp Precision Design: Random Noise",* DS01228
- **AN1297:** *"Microchip's Op Amp SPICE Macro Models"'* DS01297
- **AN1332:** *"Current Sensing Circuit Concepts and Fundamentals"'* DS01332

These application notes and others are listed in:

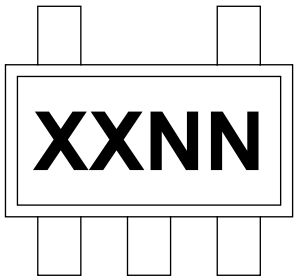
- *"Signal Chain Design Guide",* DS21825

NOTES:

6.0 PACKAGING INFORMATION

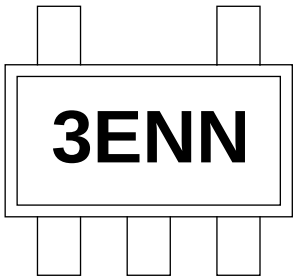
6.1 Package Marking Information

5-Lead SOT-23 (2x3)

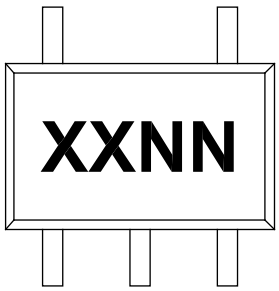


Part Number	Code
MCP6471T-E/OT	3ENN

Example:

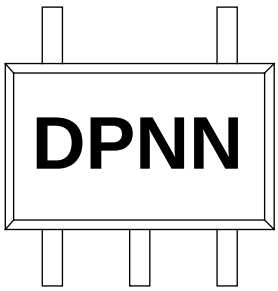


5-Lead SC-70



Part Number	Code
MCP6471T-E/LTY	DPNN

Example:

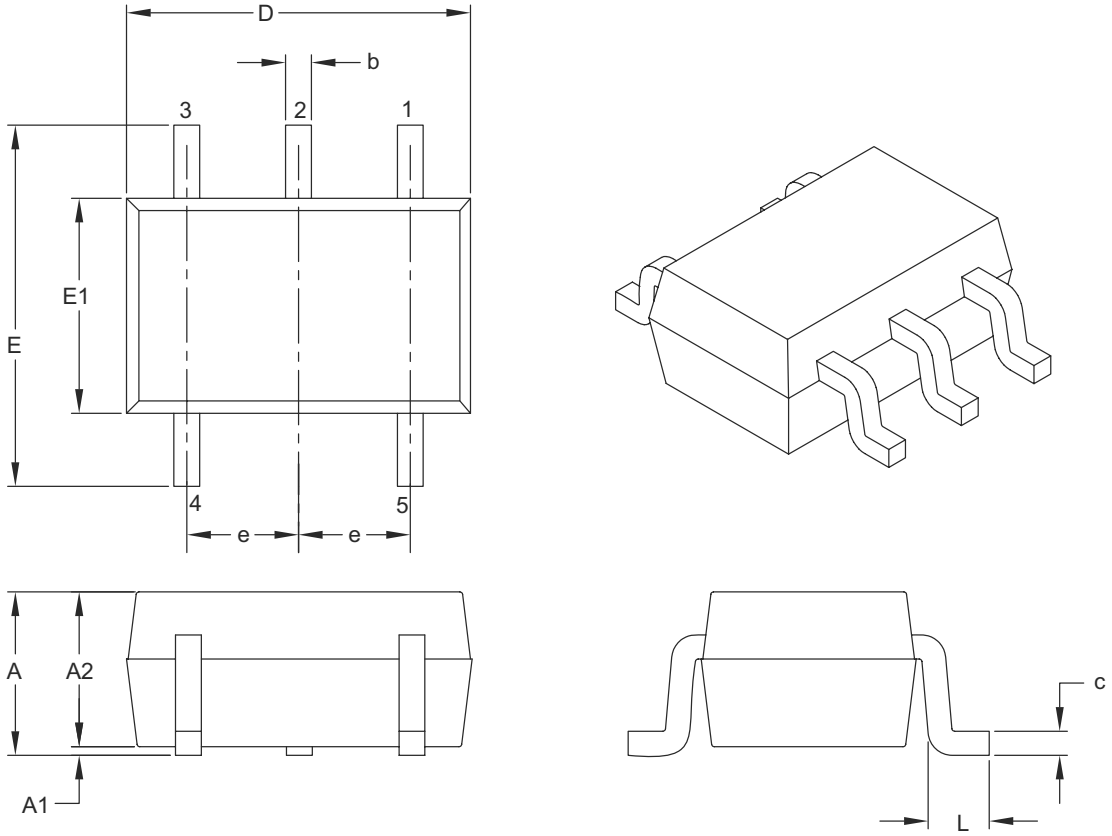


Legend:	XX...X	Customer-specific information
	Y	Year code (last digit of calendar year)
	YY	Year code (last 2 digits of calendar year)
	WW	Week code (week of January 1 is week ‘01’)
	NNN	Alphanumeric traceability code
	(e3)	Pb-free JEDEC designator for Matte Tin (Sn)
	*	This package is Pb-free. The Pb-free JEDEC designator ((e3)) can be found on the outer packaging for this package.

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

5-Lead Plastic Small Outine Transistor (LTY) [SC70]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		5	
Pitch	e		0.65 BSC	
Overall Height	A	0.80	–	1.10
Molded Package Thickness	A2	0.80	–	1.00
Standoff	A1	0.00	–	0.10
Overall Width	E	1.80	2.10	2.40
Molded Package Width	E1	1.15	1.25	1.35
Overall Length	D	1.80	2.00	2.25
Foot Length	L	0.10	0.20	0.46
Lead Thickness	c	0.08	–	0.26
Lead Width	b	0.15	–	0.40

Notes:

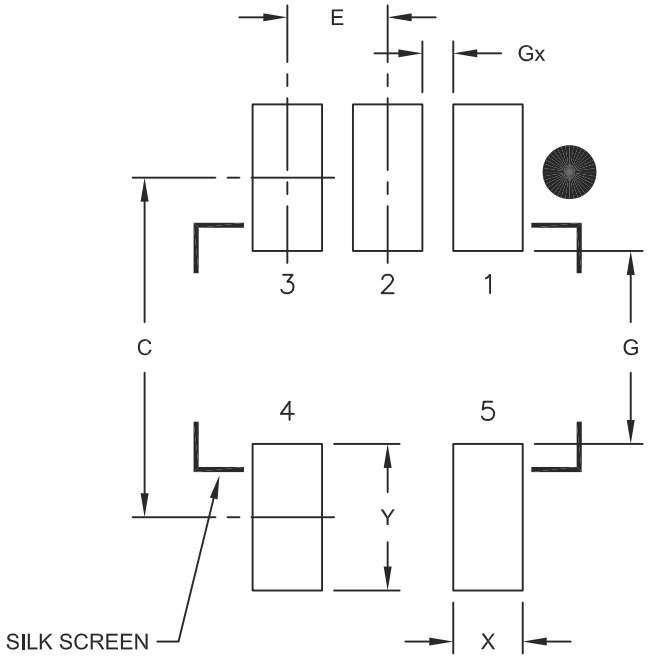
1. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.127 mm per side.
2. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-061B

5-Lead Plastic Small Outine Transistor (LTY) [SC70]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E		0.65 BSC	
Contact Pad Spacing	C		2.20	
Contact Pad Width	X			0.45
Contact Pad Length	Y			0.95
Distance Between Pads	G	1.25		
Distance Between Pads	Gx	0.20		

Notes:

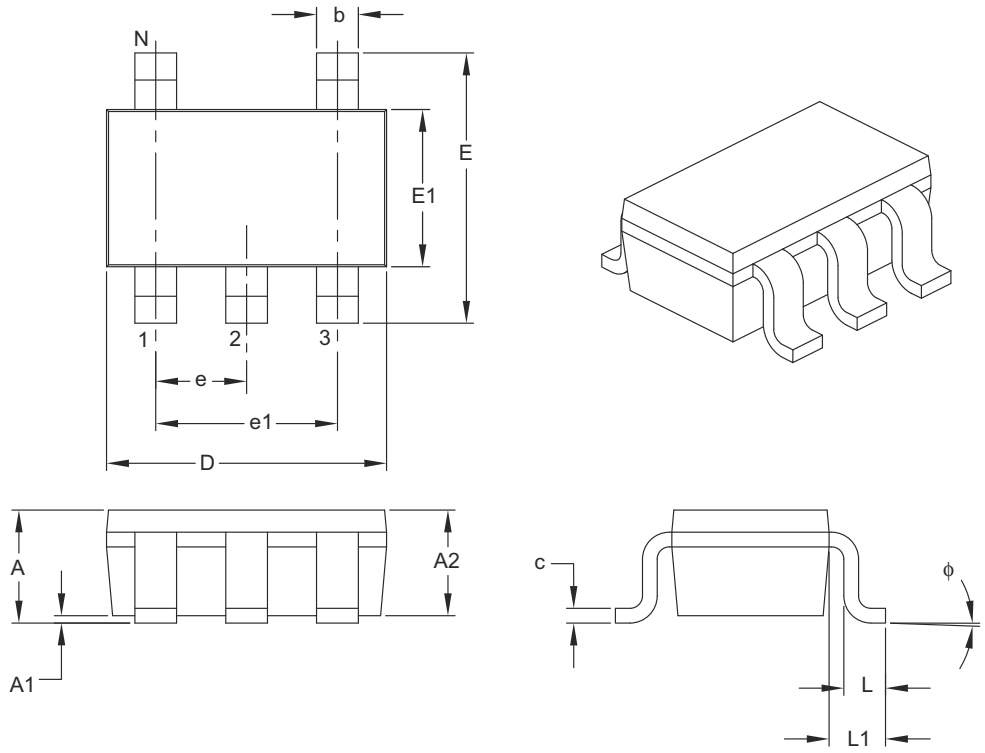
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2061A

5-Lead Plastic Small Outline Transistor (OT) [SOT-23]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		5	
Lead Pitch	e		0.95 BSC	
Outside Lead Pitch	e1		1.90 BSC	
Overall Height	A	0.90	–	1.45
Molded Package Thickness	A2	0.89	–	1.30
Standoff	A1	0.00	–	0.15
Overall Width	E	2.20	–	3.20
Molded Package Width	E1	1.30	–	1.80
Overall Length	D	2.70	–	3.10
Foot Length	L	0.10	–	0.60
Footprint	L1	0.35	–	0.80
Foot Angle	ϕ	0°	–	30°
Lead Thickness	c	0.08	–	0.26
Lead Width	b	0.20	–	0.51

Notes:

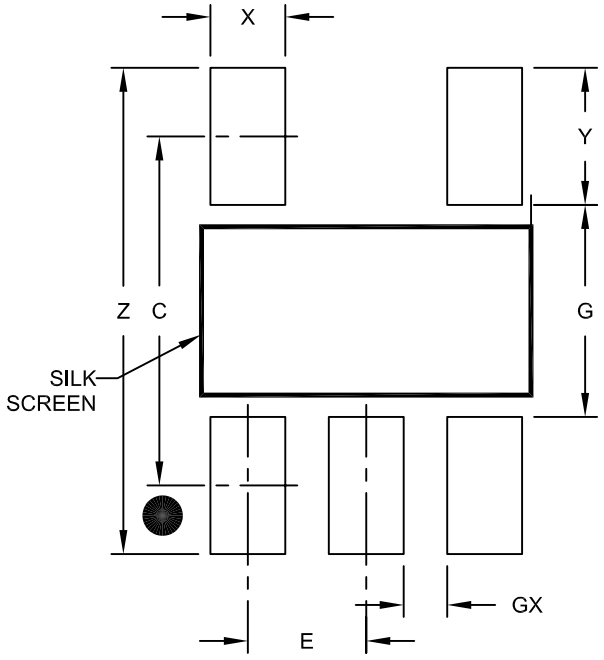
1. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.127 mm per side.
2. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-091B

5-Lead Plastic Small Outline Transistor (OT) [SOT-23]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E		0.95 BSC	
Contact Pad Spacing	C		2.80	
Contact Pad Width (X5)	X			0.60
Contact Pad Length (X5)	Y			1.10
Distance Between Pads	G	1.70		
Distance Between Pads	GX	0.35		
Overall Width	Z			3.90

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2091A

NOTES:

APPENDIX A: REVISION HISTORY

Revision B (October 2012)

The following is the list of modifications:

1. Updated the maximum low input offset voltage value in the **Section "Features"**.
2. Updated the minimum and maximum input offset voltage in **TABLE 1-1: "DC electrical specifications"**.

Revision A (September 2012)

- Original Release of this Document.

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	-X	/XX
Device	Temperature Range	Package

Device:	MCP6471T:	Single Op Amp (Tape and Reel) (SC70, SOT-23)
Temperature Range:	E =	-40°C to +125°C (Extended)
Package:	LTY =	Plastic Package (SC70), 5-lead
	OT =	Plastic Small Outline Transistor, (SOT-23), 5-lead

Examples:

a)	MCP6471T-E/LTY:	Tape and Reel, Extended Temp., 5LD SC70 package
b)	MCP6471T-E/OT:	Tape and Reel, Extended Temp., 5LD SOT-23 package

NOTES:

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- Microchip products meet the specification contained in their particular Microchip Data Sheet.
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